

Phase segregation in Mn-doped In_2O_3 : *in situ* high-pressure high-temperature synchrotron studies in multi-anvil assemblies†

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Manganese-doped bixbyite-type $\text{c-In}_2\text{O}_3$ decomposes into corundum-type $\text{rh-In}_2\text{O}_3$ and cubic MnO at 8 GPa and 950 °C.

Indium oxide (In_2O_3)—a transparent semiconductor with intrinsic n-type character—serves as a base material for diverse applications including touch displays and photovoltaics,¹ thermoelectrics,² and gas sensors.³ A great deal of time and effort has been invested worldwide in synthesizing, characterizing and modeling indium oxides. A typical approach to achieve certain functional properties is to stabilize a preferred polymorph and/or control its defect chemistry.^{1–3} Synthesis under high-pressure conditions generally allows for stabilizing solid state materials with unusual valence states and coordination numbers that are not accessible by other means. In the case of In_2O_3 -based materials, the combination of *both* approaches, *i.e.* subjecting doped and ternary indium oxides to high-pressure appears very attractive. An example is the high-pressure-assisted synthesis of indium-based perovskites (InMnO_3 , $\text{InFe}_{0.5}\text{Mn}_{0.5}\text{O}_3$ and $\text{In}_{0.7}\text{Fe}_{0.5}\text{Mn}_{0.5}\text{O}_{2.55}$) representing a new class of near-room temperature multiferroics.⁴

The goal of the present work is to study the effect of doping on the pressure-induced phase transitions in In_2O_3 . Manganese-doping was chosen for the present study because the stable ambient pressure phases of the pure oxides (hereafter denoted as $\text{c-In}_2\text{O}_3$ and $\text{c-Mn}_2\text{O}_3$) both have bixbyite-type (space group $Ia-3$, No. 206) structure but are crystallized in different structures at higher pressures and temperatures, as displayed in Fig. 1.

With increasing pressure/temperature, $\text{c-In}_2\text{O}_3$ transforms into a Rh_2O_3 -II-type ($\text{o}'\text{-In}_2\text{O}_3$, $Pbcn$, No. 60) and then to a $\alpha\text{-Gd}_2\text{S}_3$ -type ($\text{o}'\text{-In}_2\text{O}_3$, $Pnma$, No. 62) structure,^{6,7} while $\text{c-Mn}_2\text{O}_3$ crystallizes in corundum- ($R\bar{3}c$, No. 167), A-site ordered perovskite ($P\bar{1}$, No. 2) and post-perovskite ($Cmcm$, No. 63) structures.^{8,9} Manganese-doped

In_2O_3 may thus show a different transformation sequence, either crystallizing into yet another high pressure structure or decomposing into binary oxides.

In previous investigations laser-heated diamond-anvil cells (DACs) were employed to compress and heat $\text{c-In}_2\text{O}_3$ specimens.^{6–7,10–12} However, temperatures below 1000 °C, where several phase transitions in In_2O_3 are expected, are very difficult to control with this technique. Externally heated DACs may be used, but would also produce very limited amounts of a high-pressure polymorph that can be recovered to ambient conditions. A synthesis method providing both *in situ* control and macroscopic quantities of the target material, suitable for physico-chemical characterization after quenching from high pressure and temperature is available in the form of large volume (multi-anvil) presses at synchrotron facilities.¹³ For the present study, the phase development in Mn-doped $\text{c-In}_2\text{O}_3$ was followed *in situ* by energy-dispersive X-ray diffractometry at the two stage 6–8 MAX200X multi-anvil high pressure diffractometer of the GFZ Potsdam (beamline W2, HASYLAB/DESY, Hamburg, Germany).

New high-pressure/high-temperature multi-anvil assemblies for synchrotron studies developed at the Freiberg High Pressure

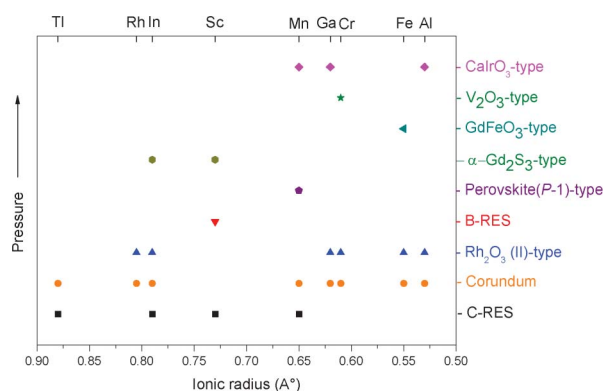


Fig. 1 Overview of ambient and high pressure crystal structures of M_2O_3 oxides with respect to the dependence on the cation radii. Corundum-type ($R\bar{3}c$, No. 167, $\text{rh-In}_2\text{O}_3$ hereafter) is metastable at all pressures.⁵

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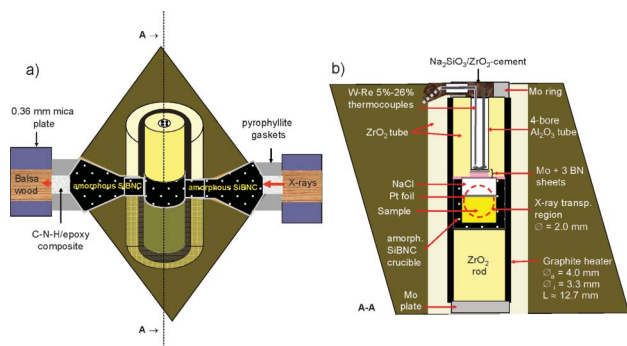


Fig. 2 Schematic cross sections of the multi-anvil octahedral pressure cell (b) and gasketing scheme (a) employed for this study. This synchrotron multi-anvil assembly comprises of only amorphous and low Z-materials along the beam path, thus providing high X-ray transmission and no additional reflections from the sample environment.¹⁴

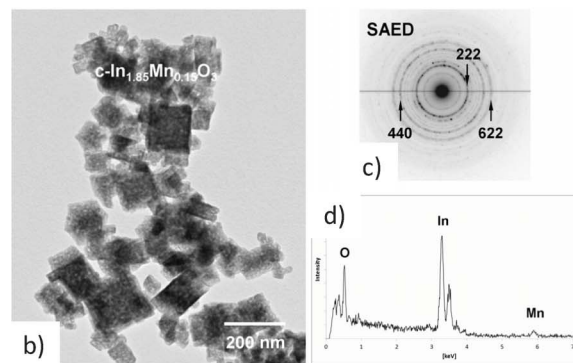
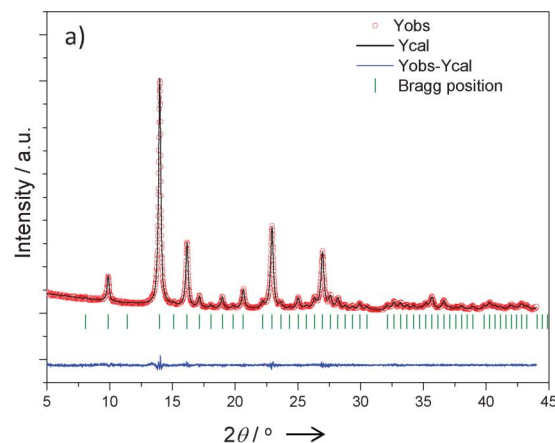
Research Centre were employed (Fig. 2).¹⁵ These assemblies have low X-ray absorption and don't show any additional reflections from the sample environment.

The initial *c*-In₂O₃ specimen doped with 7.5 at% Mn was synthesized by a hydrothermal method followed by calcination in air at 500 °C for 2 h (see Experimental part in the ESI†). Fig. 3 displays the X-ray powder diffraction pattern (XRPD) and Rietveld difference plot of the material. The structure refinement confirms a phase-pure solid solution *c*-In_{1.85}Mn_{0.15}O₃ with a slightly diminished lattice parameter ($a = 10.0922(6)$ Å) compared to that of undoped *c*-In₂O₃ ($a = 10.126(7)$ Å).⁵ This decrease is due to the substitution of Mn³⁺ for In³⁺ [$r(\text{Mn}^{3+}, \text{high spin}) = 65$ pm, $r(\text{In}^{3+}) = 79$ pm; both ions are 6-fold coordinated].¹⁶ No overstructure reflections can be seen and thus the substitution can be assumed to be close to random. Despite recent works pointing out the stabilization of Mn²⁺ in *c*-In₂O₃,¹⁷ we did not observe Mn²⁺ ions in our specimens. The large ionic radius of Mn²⁺ ions (82 pm)¹⁶ should result in an increase of the lattice parameters of indium oxide that was not observed in our experiments. Also recent UV-vis spectroscopy and magnetic characterization results confirm Mn³⁺ in *c*-In₂O₃ materials.^{18,19}

The homogeneity of the specimen was further investigated by TEM inspection (Fig. 3b–d). As shown in Fig. 3b, the specimen consists of cube-shaped crystals with a typical intrinsic porosity. The latter is due to the synthesis conditions of our specimen, that was formed upon thermal decomposition of indium hydroxide accompanied by the escape of water molecules.²⁰ The energy dispersive X-ray spectroscopy (EDS, Fig. 3d) analysis on several single crystals confirms the incorporation of manganese into the *c*-In₂O₃.

Fig. 4 shows the energy-dispersive X-ray diffraction patterns of the *c*-In_{1.85}Mn_{0.15}O₃ specimen compressed to ~8 GPa and step-wise heated up to 950 °C. These *in situ* time-resolved data at given *p*-*T* conditions demonstrate some rather unexpected behaviour of the *c*-In_{1.85}Mn_{0.15}O₃ sample.

Compression of the *c*-In_{1.85}Mn_{0.15}O₃ specimen to 8 GPa at room temperature leads to a significant broadening of the XRD reflections due to deviatoric stress; the peak positions are shifted



(c)

(d)

Fig. 3 (a) Structure refinement plot (*ex situ* powder XRD) of the initial bixbyite-type *c*-In_{1.85}Mn_{0.15}O₃ (*Ia*-3, No. 206, $Z = 16$, $a = 10.0922(6)$ Å) showing observed (red circles) and calculated (black solid line) intensities. Tick marks refer to *c*-In₂O₃ structure ($R_{\text{Bragg}} = 1.00$). (b) TEM micrograph with the corresponding SAED pattern (c). The incorporation of manganese into *c*-In₂O₃ is verified by EDS (d).

to lower *d*-spacings with increasing pressure, consistent with the previous studies' observations on compressed undoped *c*-In₂O₃.^{6,12} Subsequent heating of the specimen at this pressure leads to several consecutive effects: (i) upon heating the diffractions peaks become narrow because of the release of the internal stress, (ii) a series of new reflections appear at 700 °C; these reflections are attributed to orthorhombic indium oxyhydroxide (*o*-InOOH, *P*₂₁ *nm*, No. 31, $Z = 2$, $a = 5.2642$, $b = 4.5667$, and $c = 3.2721$ Å); the *o*-InOOH reflections disappeared again at 800 °C, (iii) at 950 °C only reflections of corundum-type *rh*-In₂O₃ are observed, (iv) the specimen rapidly quenched from 950 °C to room temperature shows only *rh*-In₂O₃ reflections. The structure refinement of this specimen recovered to the ambient pressure confirmed the *rh*-In₂O₃ (*R*3̄*c*, No. 167, $Z = 6$, $a = 5.482704(5)$ and $c = 14.505157(2)$ Å) phase and indicated the presence of about 2 wt% cubic (rock salt type) MnO (*Fm*-3*m*, No. 225, $a = 4.4464(5)$ Å) (Fig. 5a). As depicted in Fig. 5b–d, the phase separation was also detectable *via* TEM imaging. EDS revealed that the *rh*-In₂O₃ does not contain a detectable amount of Mn, but a small amount of a separate phase of pure MnO, which was also confirmed by EDS analysis, was found instead. Furthermore, a significant amount of turbostratic carbon was observed in the specimen; MnO particles were observed in the vicinity of carbon segregates. Elemental

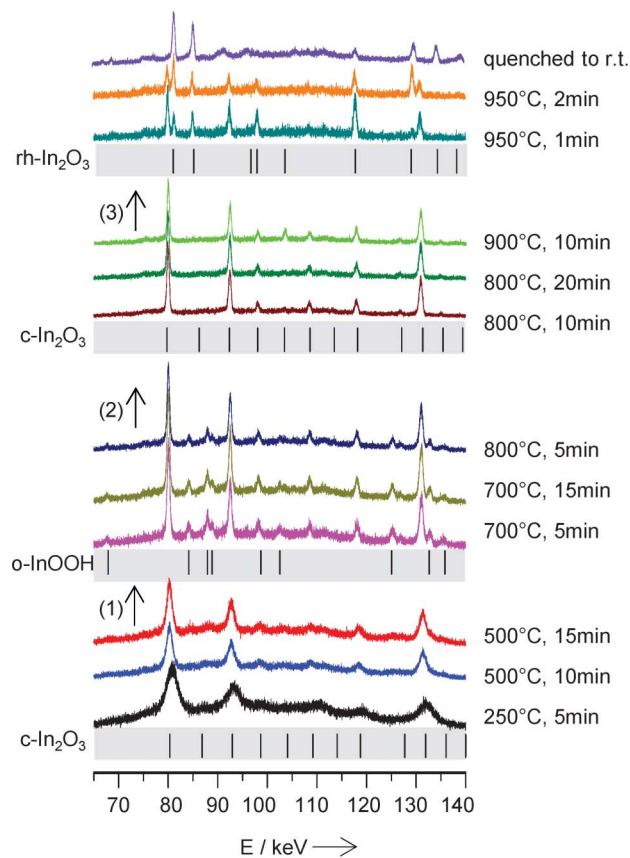


Fig. 4 Energy-dispersive XRD patterns obtained *in situ* in a multi-anvil assembly: $c\text{-In}_{1.85}\text{Mn}_{0.15}\text{O}_3$ specimen compressed at 8 GPa and step-wise heated up to 950 °C with different dwelling intervals. The tick marks refer to the calculated Bragg positions of $c\text{-In}_2\text{O}_3$, $o\text{-InOOH}$ and $\text{rh-In}_2\text{O}_3$. Arrows indicate the intermediate occurrence (1) and disappearance (2) of an $o\text{-InOOH}$ compound, and formation of corundum type $\text{rh-In}_2\text{O}_3$ (3).

carbon (graphite) as well as carbonates and acetates were not observed in the initial $c\text{-In}_{1.85}\text{Mn}_{0.15}\text{O}_3$ specimen as confirmed by elemental analysis, Raman and FTIR spectroscopy. The Raman spectra (see ESI†) confirm turbostratic carbon in the amorphous SiBCN crucibles (used in the multi-anvil assembly) and the recovered specimens, as well.

The decomposition of Mn-doped $c\text{-In}_2\text{O}_3$ into undoped $\text{rh-In}_2\text{O}_3$ and MnO is surprising. As the $\text{rh-In}_2\text{O}_3$ polymorph is metastable over the complete enthalpy–pressure diagram,⁵ the expected sequence of phase transitions with increasing pressure is $c\text{-In}_2\text{O}_3 \rightarrow o'\text{-In}_2\text{O}_3 \rightarrow o''\text{-In}_2\text{O}_3$. In another experiment, we observed that an undoped $c\text{-In}_2\text{O}_3$ specimen transforms under similar conditions (8.5 GPa/850 °C) into $o'\text{-In}_2\text{O}_3$. The metastable $\text{rh-In}_2\text{O}_3$ polymorph appears upon decompression of $o'\text{-In}_2\text{O}_3$.²¹ In the present study $\text{rh-In}_2\text{O}_3$ crystallizes upon decomposition of Mn-doped $c\text{-In}_2\text{O}_3$ at high pressure and temperature.

The formation of MnO in the recovered specimen may be explained as follows. Mn-doped $c\text{-In}_2\text{O}_3$ decomposes into undoped $\text{rh-In}_2\text{O}_3$ and Mn_2O_3 . According to a recently published p – T diagram,⁹ under the p – T conditions of our experiment Mn_2O_3 melts and irreversibly reduces to Mn_3O_4 . The further reduction of

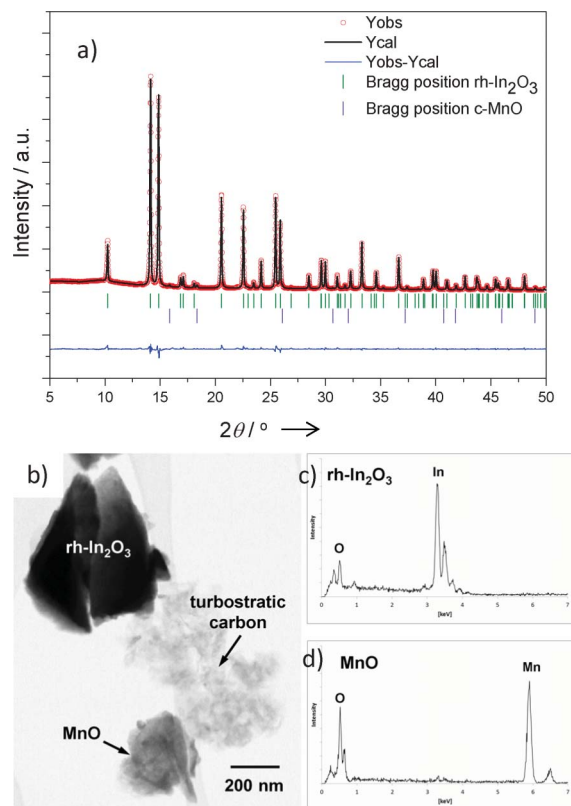


Fig. 5 (a) Structure refinement plot (*ex situ* powder XRD) of a $c\text{-In}_{1.85}\text{Mn}_{0.15}\text{O}_3$ specimen recovered after being compressed to 8 GPa and heated to 950 °C, showing observed (red circles) and calculated (black solid line) intensities. Complete phase segregation into pure $\text{rh-In}_2\text{O}_3$ ($R3c$, No. 167, $Z = 6$, $a = 5.482704(5)$ and $c = 14.505157(2)$ Å) and rocksalt-type $c\text{-MnO}$ ($a = 4.4464(5)$ Å, fraction 2.14%) is discernible. Refinement residuals were $R_{\text{Bragg}} = 2.32$ for $\text{rh-In}_2\text{O}_3$ and $R_{\text{Bragg}} = 2.64$ for $c\text{-MnO}$. (b) TEM and EDS characterization (c, d) confirm undoped $\text{rh-In}_2\text{O}_3$ and $c\text{-MnO}$ and indicate the formation of the turbostratic carbon.

Mn_3O_4 to MnO is achieved by carbon.²² The reducing conditions occurring during the synthesis stabilize MnO against reoxidation. At ambient oxygen pressure, MnO becomes stable only at $T > 1850$ K (1577 °C) which is a significantly higher temperature than that applied in our synthesis (950 °C).²³ At this temperature MnO becomes stable if $p(\text{O}_2) < 10^{-7}$ bar. It is worth noting that the recent high-pressure experiments demonstrated also the decomposition and reduction of manganese oxides.^{9,24}

Rutile-type indium oxyhydroxide (oxide-hydroxide) $o\text{-InOOH}$ appears as a transient intermediate at 8 GPa and at 700–800 °C. $o\text{-InOOH}$ is usually synthesized from $c\text{-In}(\text{OH})_3$ under solvothermal conditions/dry pressure routes at 0.1–4 GPa and 350–600 °C.²⁵ The observation of $o\text{-InOOH}$ in the present study points out the reaction between $c\text{-In}_2\text{O}_3$ and H_2O under high-pressure and high-temperature conditions. The possible sources of water can be either the pressure standard (NaCl) or the specimen itself. It is worthy of note that $o\text{-InOOH}$ was also observed as a side phase in a recent synthesis of InMnO_3 and In-Mn-Fe-O perovskites as well as corundum-type $\text{In}_{2-2x}\text{Zn}_x\text{Sn}_x\text{O}_3$ oxides performed at 6 GPa/1100–1500 °C and 7 GPa/1000 °C, respectively.^{26–28} Hence, the appearance of $o\text{-InOOH}$ under high-pressure high-temperature

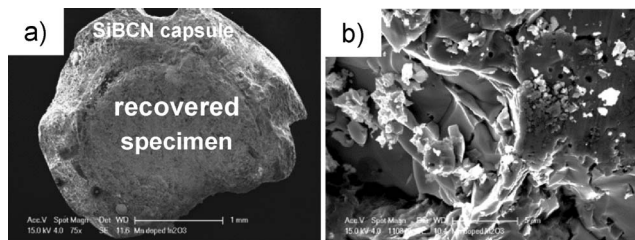


Fig. 6 Scanning electron micrographs of the specimens recovered from the *in situ* multi-anvil in SiBCN capsule (a) and high magnification images of recovered specimen (b).

conditions in indium-containing specimens can be an issue for the synthesis of binary and ternary indium oxides and requires further, more careful, study.

The scanning electron micrographs (Fig. 6) visualize the amount of the specimen recovered from the *in situ* multi-anvil experiment. Fig. 6 a shows a cross-section of the SiBCN-crucible with the recovered specimen. The apparent porosity in Fig. 6 b may indicate water evaporation from the cell which in turn may go along with crystallization of o-InOOH and/or carbon oxides released during the MnO formation.

In summary, our *in situ* time-resolved characterization of Mn-doped bixbyite-type $c\text{-In}_2\text{O}_3$ at 8 GPa indicates two effects: (i) the appearance of indium oxyhydroxide (InOOH) as a transient intermediate at 700–800 °C and (ii) decomposition of the initial material into undoped corundum-type $\text{rh-In}_2\text{O}_3$ and MnO at 950 °C. The reduction of Mn^{3+} (in $c\text{-In}_2\text{O}_3$) to Mn^{2+} (in Mn_3O_4 and MnO) is explained by the interplay of two processes, *i.e.* the thermodynamic stability of Mn_3O_4 under particular p - T conditions and the reaction of Mn_3O_4 with carbon from the SiBCN crucible.

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